

High Voltage LED Series Chip on Board

LCo8oD



High efficacy COB LED package
well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability



Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination

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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T_A	-40 ~ +105	°C	-
Storage Temperature	T_{stg}	-40 ~ +120	°C	-
LED Junction Temperature	T_J	140	°C	-
Case Temperature	T_C	105	°C	-
Forward Current	I_F	2760	mA	-
Power Dissipation	P_D	232.6	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics ($I_F = 1620$ mA, $T_A = 85$ °C)

Item	Unit	Rank	Min.	Typ.	Max.
Forward Voltage (V_F)	V	1Z	47.8	52	56.2
Color Rendering Index (R_a)	-	5	80	-	-
		7	90	-	-
Thermal Resistance (junction to chip point)	°C/W		-	0.5	-
Beam Angle	°		-	115	-
Working Voltage for Insulation	V				50
Nominal Power	W			84.2	

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_J = T_C = T_A = 85$ °C)
- 2) Samsung maintains measurement tolerance of: forward voltage = ±5 %, CRI = ±1
- 3) Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.

c) Luminous Flux Characteristics (I_F = 1620 mA)

CRI (R _a) Min.	Nominal CCT (K)	Flux Rank	Flux @ T _c = 85 °C (lm)		
			Min.	Typ.	Max.
80	2700	T1	10108	10612	-
	3000	T6	10669	11201	-
	3500	T9	10992	11533	-
	4000	U2	11220	11780	-
	5000	U2	11286	11847	-
	5700	V0	11343	11904	-
	6500	V5	11172	11723	-
70	3000	U5	11514	12084	-
	4000	U9	11894	12483	-
	5000	V0	12075	12673	-

Notes:

- 1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature (T_J = T_C = 85 °C).
- 2) Samsung maintains measurement tolerance of: Luminous flux = ±7 %, CRI = ±1

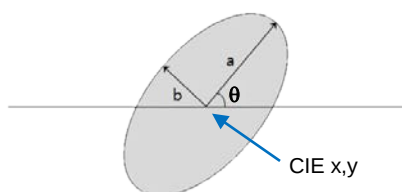
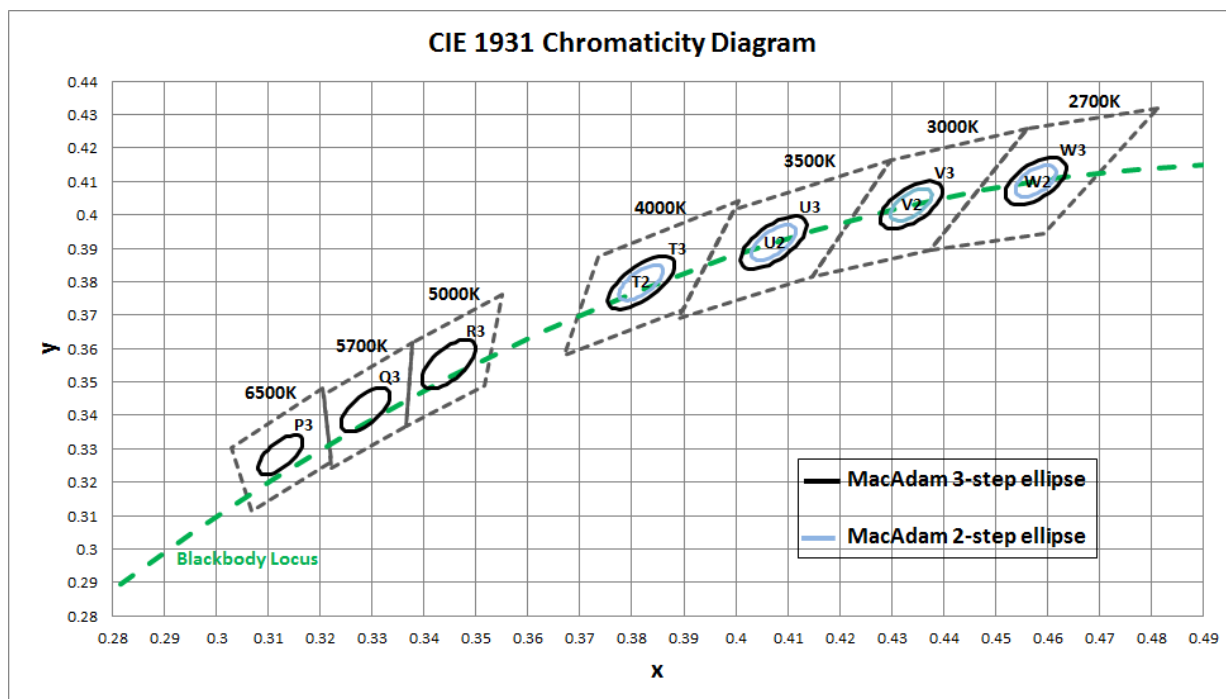
2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	W	H	A	H	D	N	M	2	5	1	Z	W	3	R	7

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	A	
7 8	Form Factor	HD	COB
9	Lens Type	N	No lens
10	Wattage or Model	M	LC080D
11	Internal Code	2	
12	CRI & Sorting Temperature	3	Min. 70 (85°C)
		5	Min. 80 (85°C)
13 14	Forward Voltage (V)	1Z	47.8~56.2
15	CCT (K)	W V U T R Q P	2700K 3000K 3500K 4000K 5000K 5700K 6500K
16	MacAdam Step	3	MacAdam 3-step
17 18	Luminous Flux	T1 T6 T9 U2 V0 V5 U5 U9 V0	Min. 10100 Min. 10600 Min. 10900 Min. 11200 Min. 11300 Min. 11100 Min. 11500 Min. 11800 Min. 12000

a) Binning Structure ($I_F = 1620 \text{ mA}$, $T_C = 85 \text{ }^\circ\text{C}$)

CRI (R_a) Min.	Nominal CCT (K)	Product Code	V_F Rank	Chrom. Bin	Flux Rank	Flux Range (Φ_v , lm)
80	2700	SPHWHAHDNM251ZW2T1	1Z	W3	T1	10108 ~
		SPHWHAHDNM251ZW3T1		W2		
	3000	SPHWHAHDNM251ZV2T6	1Z	V3	T6	10669 ~
		SPHWHAHDNM251ZV3T6		V2		
	3500	SPHWHAHDNM251ZU2T9	1Z	U3	T9	10992 ~
		SPHWHAHDNM251ZU3T9		U2		
	4000	SPHWHAHDNM251ZT2U2	1Z	T3	U2	11220 ~
		SPHWHAHDNM251ZT3U2		T2		
	5000	SPHWHAHDNM251ZR3U2	1Z	R3	U2	11286 ~
	5700	SPHWHAHDNM251ZQ3V0	1Z	Q3	V0	11343 ~
	6500	SPHWHAHDNM251ZP3V5	1Z	P3	V5	11172 ~
70	3000	SPHWHAHDNM231ZV3U5	1Z	V3	U5	11514 ~
	4000	SPHWHAHDNM231ZT3U9	1Z	T3	U9	11894 ~
	5000	SPHWHAHDNM231ZR3V0	1Z	R3	V0	12075 ~

b) Chromaticity Region & Coordinates ($I_F = 1620 \text{ mA}$, $T_J = 85^\circ\text{C}$)


MacAdam Ellipse (W2, W3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4578	0.4101	53.70	0.0054	0.0028
3-step	0.4578	0.4101	53.70	0.0081	0.0042

MacAdam Ellipse (V2, V3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4338	0.403	53.22	0.0056	0.0027
3-step	0.4338	0.4030	53.22	0.0083	0.0041

MacAdam Ellipse (U2, U3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4073	0.3917	54.00	0.0062	0.0028
3-step	0.4073	0.3917	54.00	0.0093	0.0041

MacAdam Ellipse (T2, T3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.3818	0.3797	53.72	0.0063	0.0027
3-step	0.3818	0.3797	53.72	0.0094	0.0040

MacAdam Ellipse (R3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3447	0.3553	59.62	0.0082	0.0035

MacAdam Ellipse (Q3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3287	0.3417	59.0950	0.0075	0.0032

MacAdam Ellipse (P3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3123	0.3282	58.5700	0.0067	0.0029

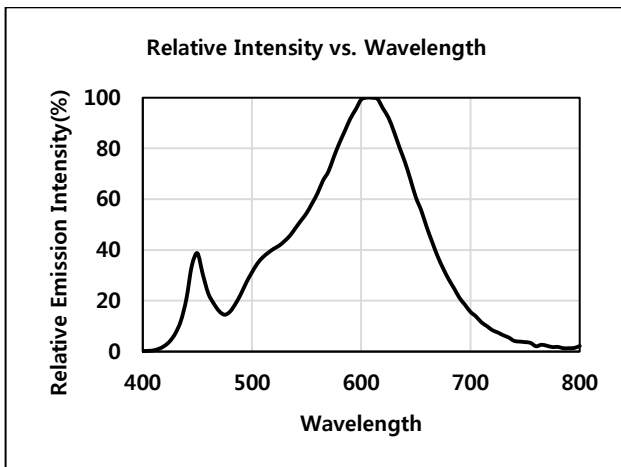
Note:

Samsung maintains measurement tolerance of: $C_x, C_y = \pm 0.005$

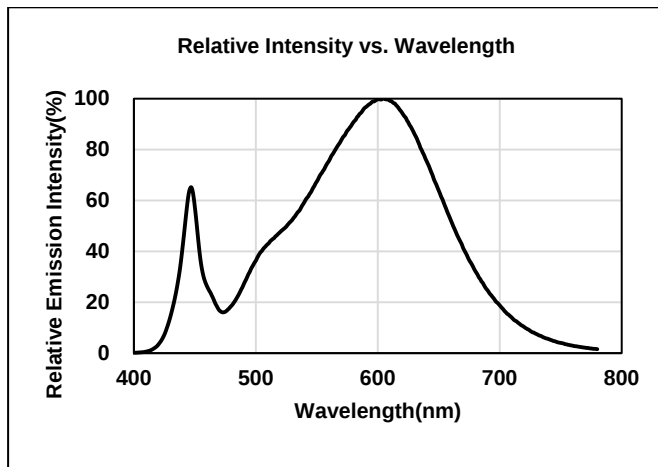
3. Typical Characteristics Graphs

a) Spectrum Distribution ($I_F = 1620 \text{ mA}$, $T_J = 85^\circ\text{C}$)

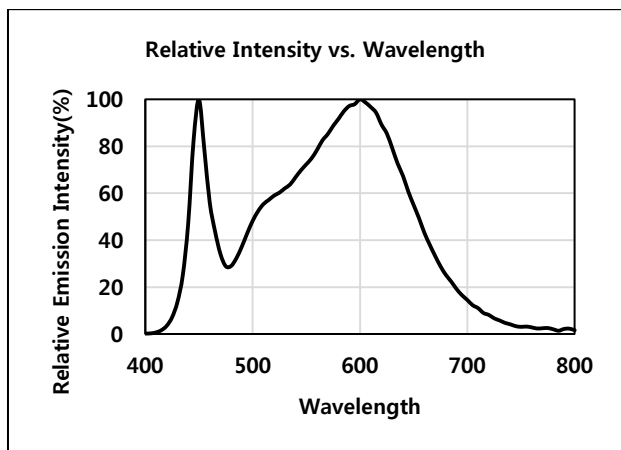
CCT: 2700 K (80 CRI)



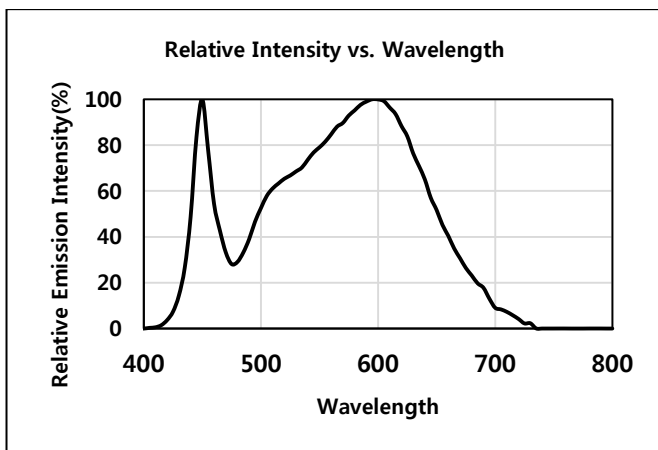
CCT: 3000 K (80 CRI)



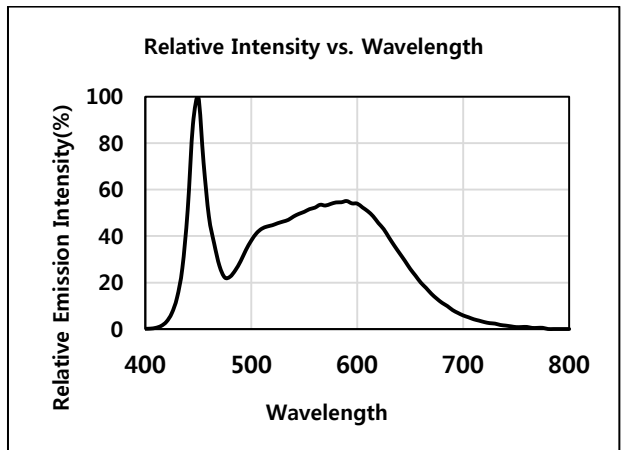
CCT: 3500 K (80 CRI)



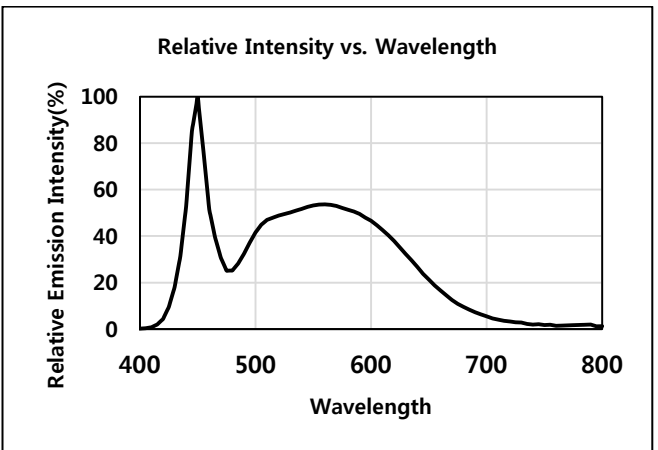
CCT: 4000 K (80 CRI)



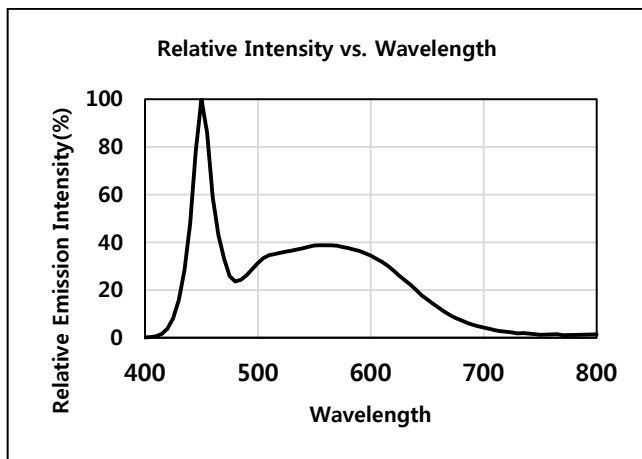
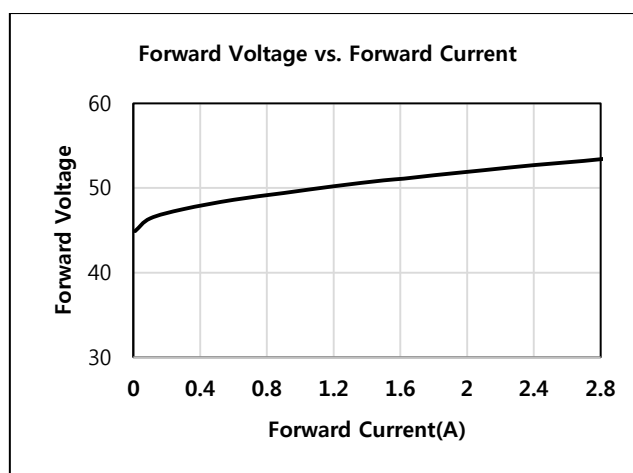
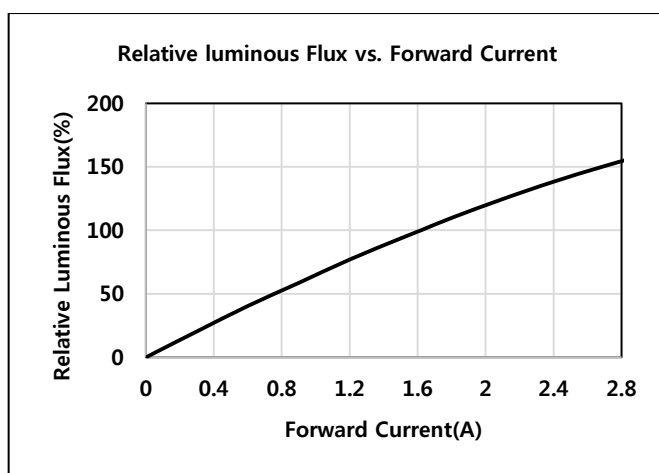
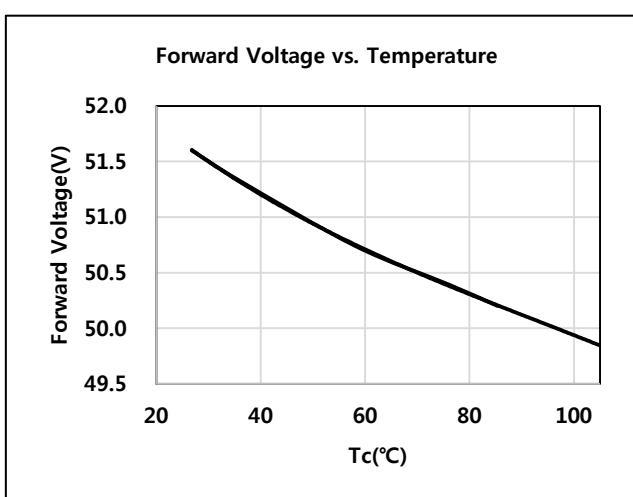
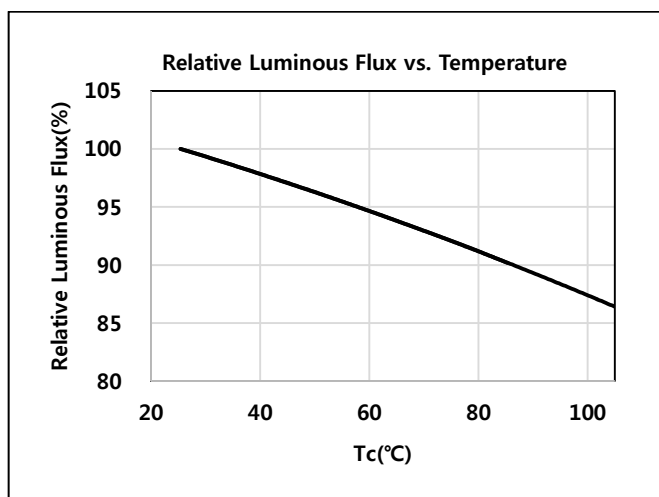
CCT: 5000 K (80 CRI)



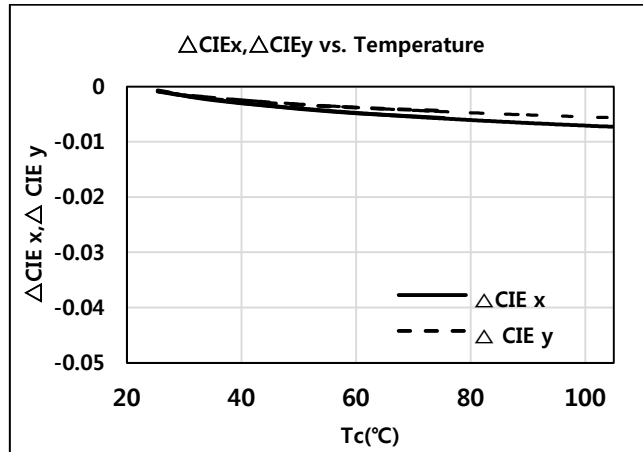
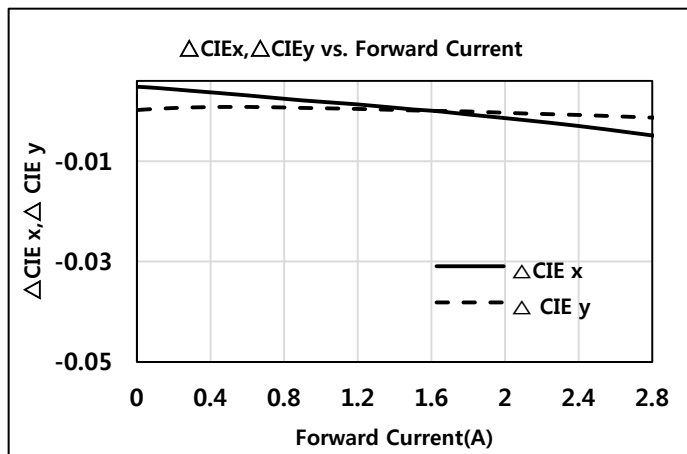
CCT: 5700 K (80 CRI)



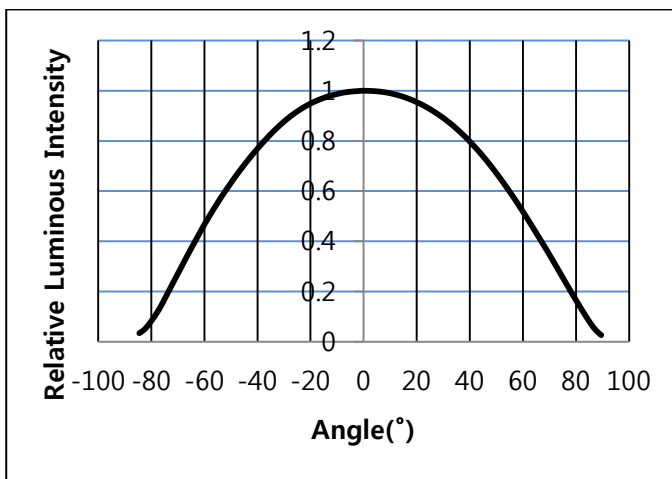
CCT: 6500 K (80 CRI)

b) Forward Current Characteristics ($T_J = 85^\circ\text{C}$)c) Temperature Characteristics ($I_F = 1620\text{mA}$)

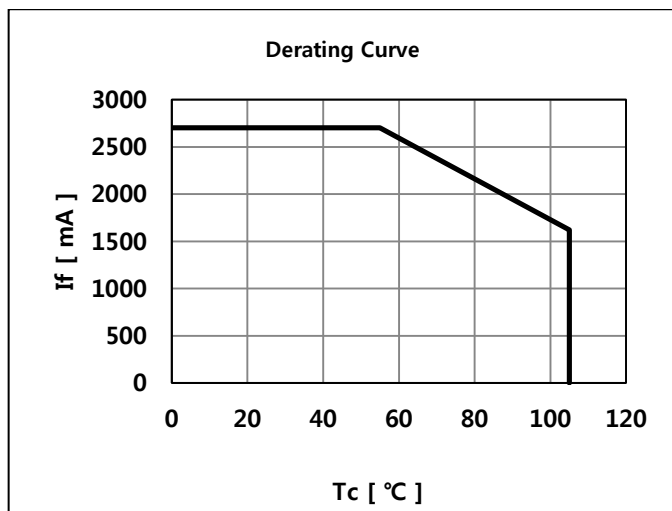
d) Color Shift Characteristics ($T_J = 25\text{ }^{\circ}\text{C}$, $I_F = 1620\text{mA}$, CRI80+)



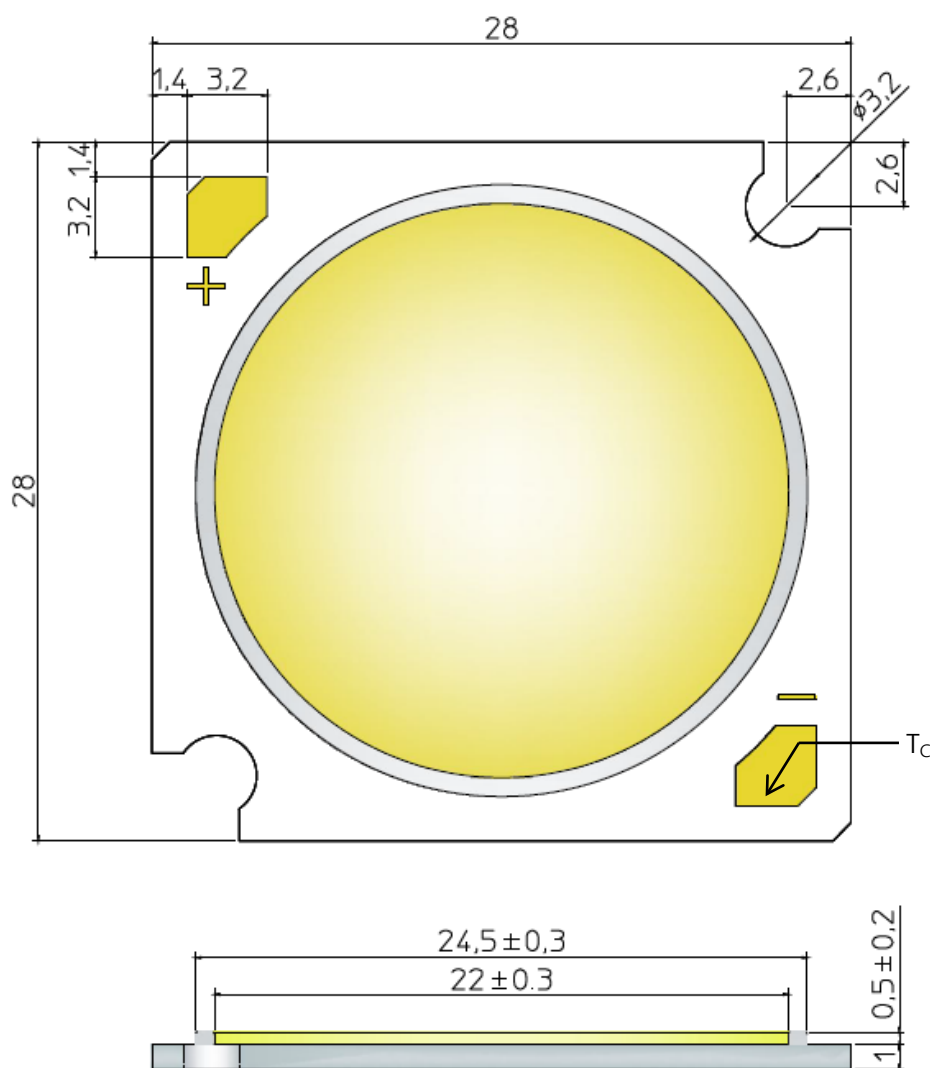
e) Beam Angle Characteristics ($I_F = 1620\text{ mA}$, $T_J = 85\text{ }^{\circ}\text{C}$)



f) Derating Characteristics



4. Outline Drawing & Dimension



1. Unit: mm
2. Tolerance: ± 0.3 mm

Item	Dimension	Tolerance	Unit
Length	28.0	± 0.15	mm
Width	28.0	± 0.15	mm
Height	1.50	± 0.20	mm
Light Emitting Surface (LES) Diameter	22.0	± 0.30	mm

Note: Denoted product information above is only an example
(LC080D, CRI80+, 3000K)

5. Reliability Test Items & Conditions

a) Test Items

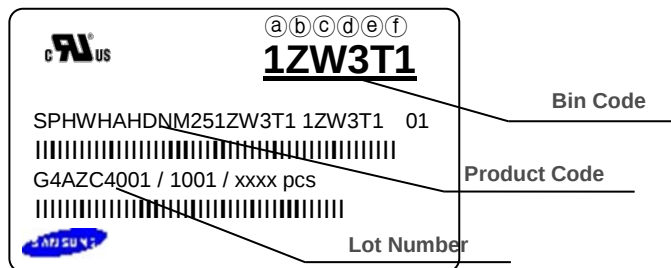
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 °C, 90 % RH., DC Derating, I_F	1000 h
High Temperature Life Test	85 °C, DC Derating, I_F	1000 h
Low Temperature Life Test	-40 °C, DC , $I_F = 1944$ mA	1000 h
Pulsed Operating Life Test	55 °C, Pulse width 100 μ s, duty cycle 3 %	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Temperature Humidity Storage	60 °C, 90% RH	1000h
Thermal Cycle	-45 °C / 15 min $\leftrightarrow$ 125 °C / 15 min temperature change in 5 min	500 cycles
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 30 min transfer power on/off each 5 min, DC Derating, $I_F = \text{max}$	100 cycles
ESD (HBM)	R_1 : 10 M Ω R_2 : 1.5 k Ω C: 100 pF V: ± 2 kV	5 times
ESD (MM)	R_1 : 10 M Ω R_2 : 0 k Ω C: 200 pF V: ± 0.2 kV	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency $\leftrightarrow$ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H ₂ S 15 ppm	504h

b) Criteria for Judging the Damage

Item	Symbol	Test Condition ($T_c = 25$ °C)	Limit	
			Min.	Max.
Forward Voltage	V_F	$I_F = 1620$ mA	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φ_v	$I_F = 1620$ mA	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure



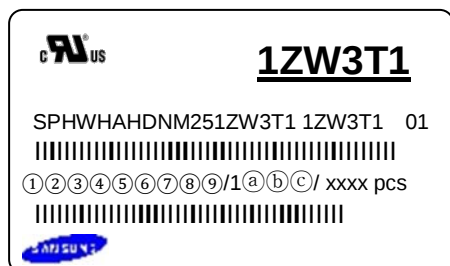
Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

- ⒶⒷ: Forward Voltage bin (refer to page 11)
- ⒸⒹ: Chromaticity bin (refer to page 9-10)
- ⒺⒻ: Luminous Flux bin (refer to page 6)

b) Lot Number

The lot number is composed of the following characters:



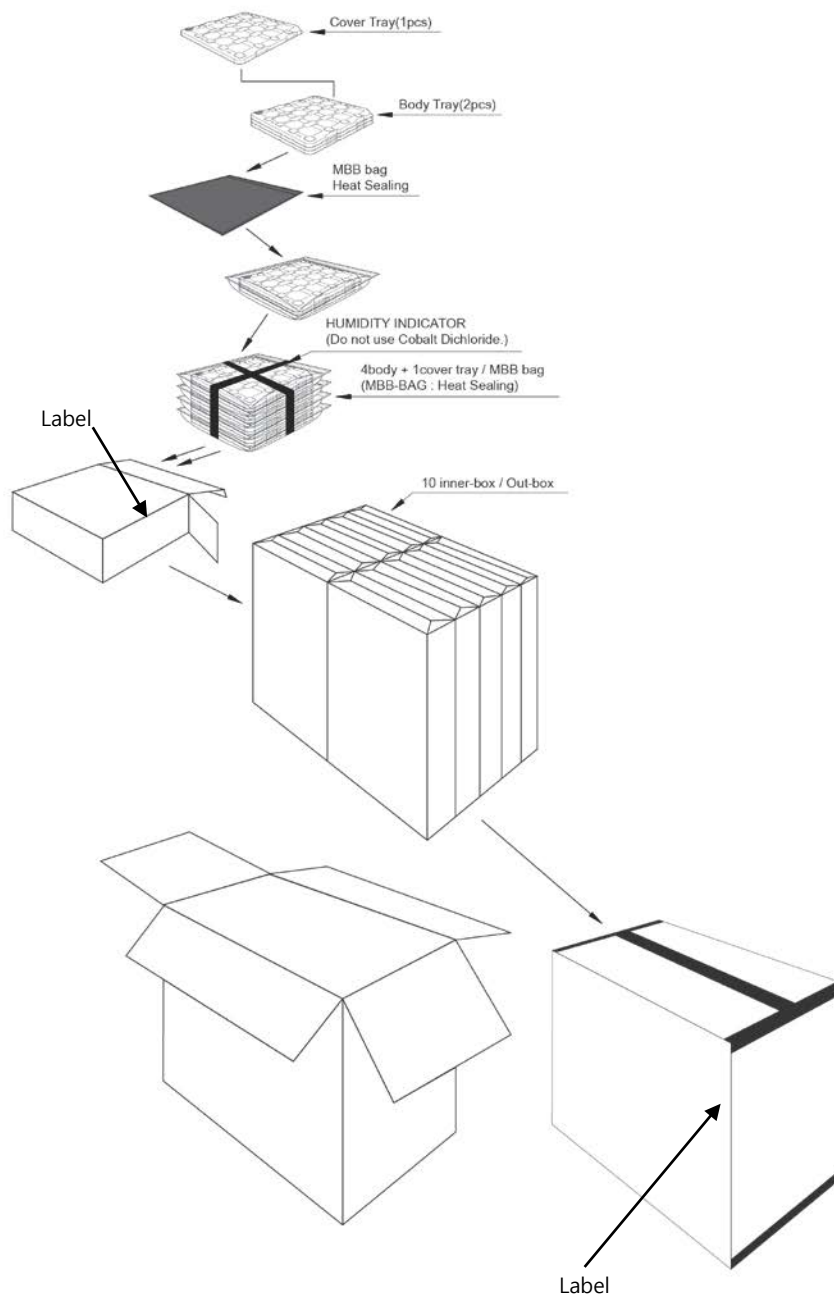
① ③④⑤⑥⑦⑧⑨ / 1ⒶⒷⒸ / xxxx pcs

- ① : Production site (S: Giheung, Korea, G: Tianjin, China)
- ② : 4 (LED)
- ③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
- ④ : Year (Z: 2015, A: 2016, B: 2017...)
- ⑤ : Month (1~9, A, B, C)
- ⑥⑦⑧⑨ : Day (1~9, A, B~V)
- ⒶⒷⒸ : Product serial number (001 ~ 999)

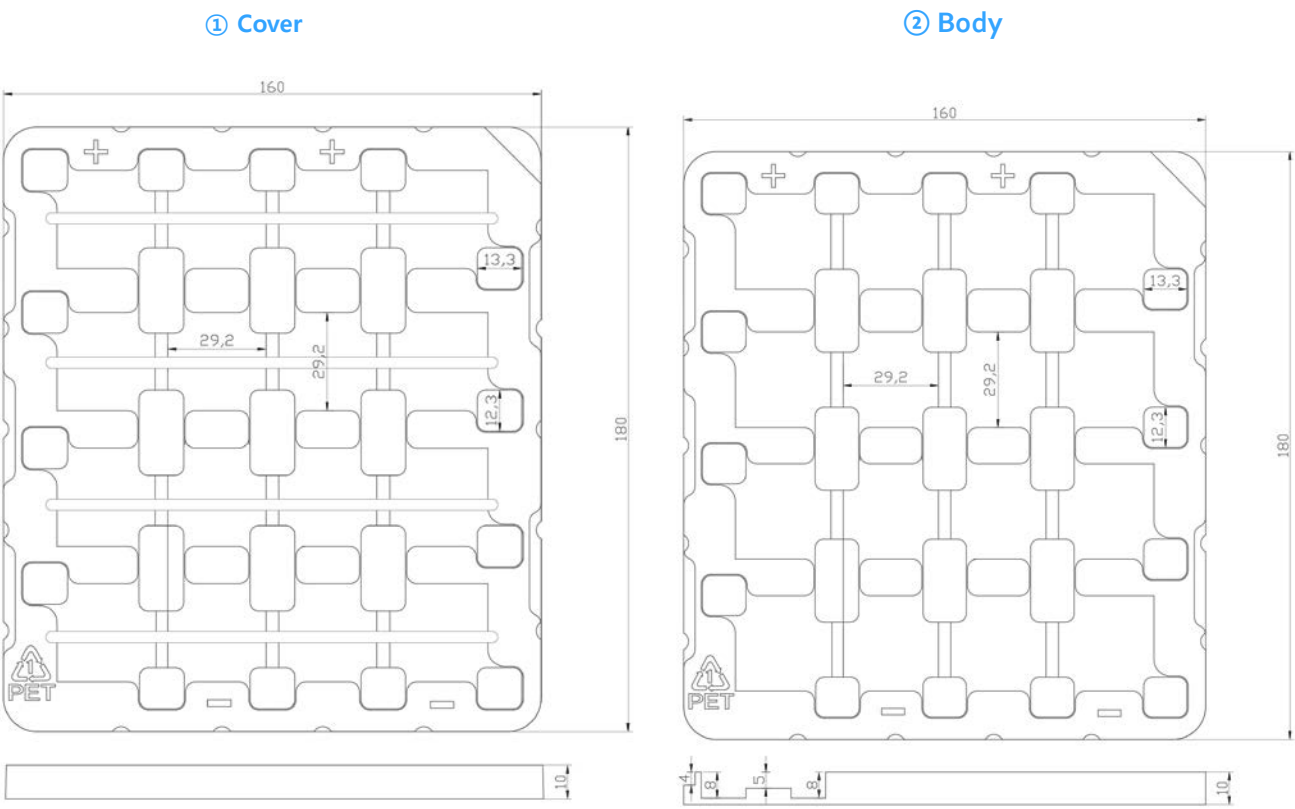
6. Packing Structure

Packing material	Max. quantity in pcs of COB	Dimension(mm)			
		Length	Width	Height	Tolerance
Tray	16	160	180	10	1.0
Aluminum Bag	32(2 trays)	210	241		10
Inner Box	128	230	84	260	2
Outer Box	1280	476	445	272	5

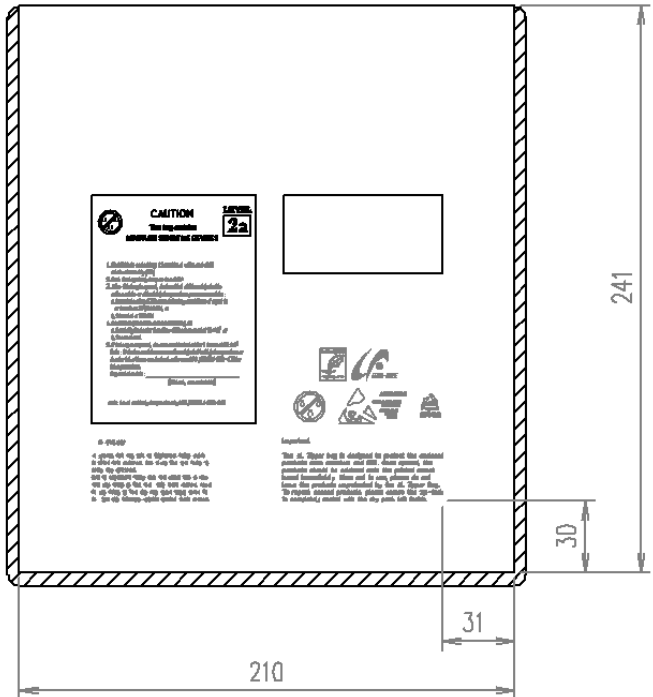
a) Packing Structure



b) Tray

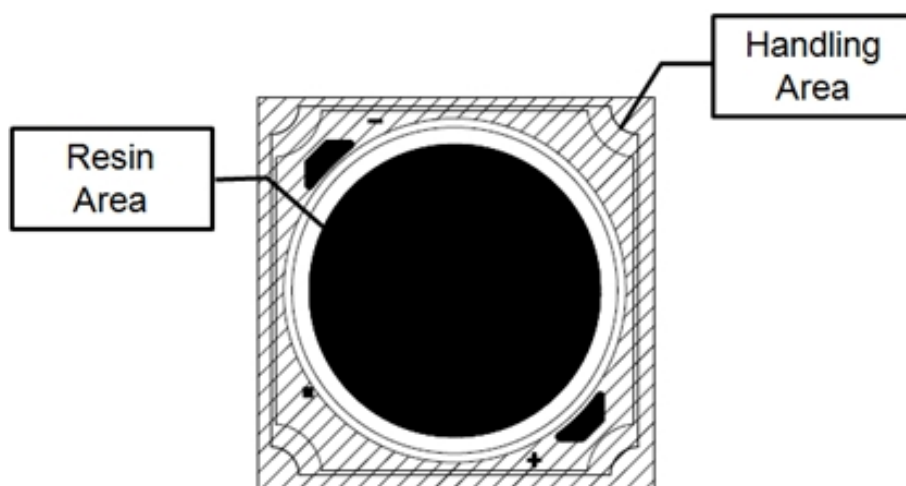


c) Aluminum Vinyl Packing Bag



8. Precautions in Handling & Use

- 1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 6) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 9) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



Legal and additional information.

About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors. We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

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